NSN 5961-00-499-7418

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-499-7418 **Inclosure Material:** Glass **Overall Length:** 0.422 inches **Overall Diameter:** 0.240 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 1.00 amperes forward current, average peak **Power Rating Per Characteristic:** 3.1 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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